										RE	VISI	ONS	3												
LTR	I	DESCRIPTION											DATE	(YR-	MO-D/	A)	AP	PRO	VED						
Α	and d	Page 4, Table I, change conditions for Zener voltage. Change and delete subgroups 5 and 6 for reverse dynamic impedance test. Change code ident. No. to 67268.										,													
В		Add footnote for reverse dynamic impedance test. Editorial changes throughout. 1988 MARCH 27																							
												-													
CU	IRRE	:N7	Г СА	GE	C	OE	E	67	26	8															
CU	IRRE	:N7	Γ CA	GE	E C	OE	E	67	26	8															Ţ
REV		:N7	Γ CA	GE	C	OE	E	67	26	8	-														Ī
REV SHEET		:N7	Γ CA	GE	C	OE	E	67	26	8															
REV SHEET REV	т	:N7		GE	C	OE	E	67	26																
REV SHEET REV SHEET	TATUS	:NT	Γ CA	GE	В	В	В	В		В															
	TATUS	N I			B 1	B 2	B 3	B 4	26		7														
REV SHEET REV SHEET REV STOF SH	TATUS HEETS	RD	REV SHEET		B 1	В	B 3 D BY	B 4		В	7			CRO	CIR	CUIT	DAY	TON,	OHK	S SUF D 454	TAGE	E RE			
REV SHEET REV SHEET OF SH PMIC I	TATUS IEETS N/A ANDA MILIT	RD FAR WIN	REV SHEET PIZED RY IG VAILABLE PARTMEN OF THE	E	B 1 APP	B 2 PARE	B 3 By By B B B B B B B B B B B B B B B	B 4 A PROMER 1	5	В	7		/D:	CRO	CIR	CUIT	S, MON	TON,	AR, THIC	VOL SIL	TAGE	E RE	FERE	NCE	

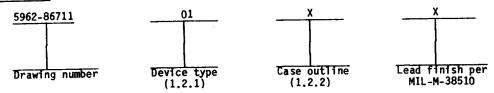
DESC FORM 193-1 SEP 87

* U.S. GOVERNMENT PRINTING OFFICE: 1987 — 748-129/60912 5962-E736

1. SCOPE

 $1.1\,$ Scope. This drawing describes device requirements for class B microcircuits in accordance with $1.\overline{2.1}$ of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices".

1.2 Part number. The complete part number shall be as shown in the following example:



1.2.1 Device types. The device types shall identify the circuit function as follows:

Device type	Generic number	Circuit function
01	LM113	Voltage reference diode
02	LM113-1	Voltage reference diode
03	LM113-2	Voltage reference diode

1.2.2 Case outline. The case outline shall be as designated in appendix C of MIL-M-38510, and as follows:

Outline letter

x See figure 1, TO-46 (2-lead can)

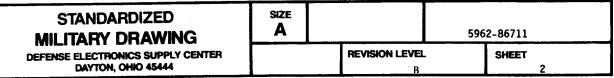
1.3 Absolute maximum ratings.

	100 11 1 /
Power dissipation (PD)	100 mW <u>1</u> /
Dougnes current	50 mA
Forward current	50 mA
Forward current	
Junction temperature	+150°C -65°C to +150°C
Storage temperature	-65 C to +150 C
Lead temperature (soldering 10 seconds)	300°C
Thermal resistance:	9 - 4 -
Junction to case (θ_{1C})	80 C/W
Junction to case (θ_{JC}) Junction to ambient (θ_{JA})	440°C/W
OUTICUTOR TO AMERICA VIJA	•

1.4 Recommended operating conditions.

Ambient operating temperature range (T_A) - - - - - - - - -55 $^{\circ}$ C to 125 $^{\circ}$ C

1/ Rating applies at 25°C ambient, without heat sink. For operating at elevated temperature the device must be derated based on a 150°C maximum junction and a thermal resistance of 80°C/W junction to case or 440°C/W junction to ambient.



2. APPLICABLE DOCUMENTS

2.1 Government specification and standard. Unless otherwise specified, the following specification and standard, of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATION

MILITARY

MIL-M-38510

- Microcircuits, General Specification for.

STANDARD

MILITARY

MIL-STD-883

- Test Methods and Procedures for Microelectronics.

(Copies of the specification and standard required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.

3. REQUIREMENTS

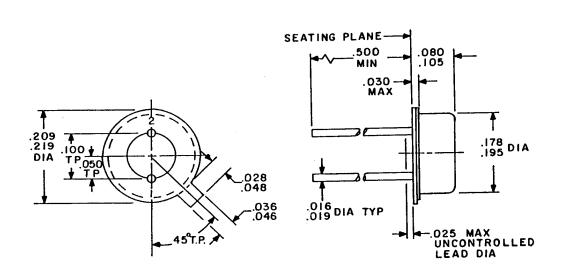
- 3.1 Item requirements. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein.
- 3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 and herein.
- 3.2.1 Case outline and terminal connections. The case outline and terminal connections shall be as specified on figure 1.
 - 3.2.2 Case outline. The case outline shall be in accordance with 1.2.2 herein.
- 3.3 Electrical performance characteristics. Unless otherwise specified, the electrical performance characteristics are as specified in table I and apply over the full ambient operating temperature range.
- 3.4 Marking. Marking shall be in accordance with MIL-STD-883 (see 3.1 herein). The part shall be marked with the part number listed in 1.2 herein. In addition, the manufacturer's part number may also be marked as listed in 6.4 herein.
- 3.5 Certificate of compliance. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in 6.4. The certificate of compliance submitted to DESC-ECS prior to listing as an approved source of supply shall state that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.
- 3.6 Certificate of conformance. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.
- 3.7 Notification of change. Notification of change to DESC-ECS shall be required in accordance with MIL-STD-883 (see 3.1 herein).

STANDARDIZED MILITARY DRAWING	SIZE A		596	2-86711	
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL	B	SHEET	3

Test	Device	Group A	Lin	nits	Unit		
1636	Symbol 	Conditions 1/ -55°C < T _A < +125°C unless otherwise specified		subgroups	Min		
Zener voltage	I V _{ZR} 	IIR = 1 mA	01	1 2,3	1.16		٧
	 		02	1 2,3	1.210		
			03	1 2,3		1.245 1.246	
Zener voltage change	ΔV _{ZR}	.5 mA <u>< I_R <</u> 20 mA	ALL	1]	15	mV
	 	.5 mA ≤ I _R ≤ 10 mA		2,3		 	
Forward voltage drop	 V _F 	 IF = 1 mA	 ALL 	 1, 2, 3 	1 	1	 V
Reverse dynamic impedance	I R _R	$I_R = 1 \text{ mA} \qquad \underline{2}/$	 ALL 	4		1	l lohm l
	İ	$I_R = 10 \text{ mA} 2/$	İ	4	i 1	.8	ĺ

- 1/ At high currents, breakdown voltage should be measured with lead lengths less than 1/4 inch. Kelvin contact sockets are also recommended. The diode should not be operated with shunt capacitances between 200 pF and 0.1 μF , unless isolated by at least a 100Ω resistor, as it may oscillate at some currents.
- 2/ Guaranteed if not tested.
 - 4. QUALITY ASSURANCE PROVISIONS
- 4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein).
- 4.2 Screening. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:
 - a. Burn-in test, method 1015 of MIL-STD-883.
 - (1) Test condition B or C using the circuit submitted with the certificate of compliance (see 3.5 herein).
 - (2) $T_A = +125^{\circ}C$, minimum.
 - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.

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METAL CAN PACKAGE

•	Inches	mm	Inches	mm
A A A A A A A A A A A A A A A A A A A	.016	0.41	.080	2.03
(太)	.019	0.48	.100	2.54
$\backslash \top /$.025	0.64	.105	2.67
©	.028	0.28	.178	4.52
NOTE: DIN O CONNECTED	.030	0.76	.195	4.95
NOTE: PIN 2 CONNECTED TO CASE	.036	0.91	.209	5.31
TO CASE	.046	1.17	.219	5.56
TOD VIEW	.048	1.22	.500	12.70
TOP VIEW	.050	1.27		

NOTES:

- Dimensions are in inches.
 Metric equivalents are given for general information only.

FIGURE 1. Case outline and terminal connections.

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- 4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method $\overline{5005}$ of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.
 - 4.3.1 Group A inspection.
 - a. Tests shall be as specified in table II herein.
 - b. Subgroups 5, 6, 7, 8, 9, 10, and 11 in table I, method 5005 of MIL-STD-883 shall be omitted.
 - 4.3.2 Groups C and D inspections.
 - a. End-point electrical parameters shall be as specified in table II herein.
 - b. Steady-state life test conditions, method 1005 of MIL-STD-883:
 - (1) Test condition B or C using the circuit submitted with the certificate of compliance (see 3.5 herein).
 - (2) $T_A = +125$ °C, minimum.
 - (3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

TABLE II. Electrical test requirements.

MIL-STD-883 test requirements	Subgroups (per method 5005, table I)
Interim electrical parameters (method 5004)	
Final electrical test parameters (method 5004)	1*,2,3,4
Group A test requirements (method 5005)	1,2,3,4
Groups C and D end-point electrical parameters (method 5005)	1,2,3,4

^{*}PDA applies to subgroup 1.

5. PACKAGING

- 5.1 Packaging requirements. The requirements for packaging shall be in accordance with ${\tt MIL-M-38510}$.
 - 6. NOTES
- 6.1 Intended use. Microcircuits conforming to this drawing are intended for use when military specifications do not exist and qualified military devices that will perform the required function are not available for OEM application. When a military specification exists and the product covered by this drawing has been qualified for listing on QPL-38510, the device specified herein will be inactivated and will not be used for new design. The QPL-38510 product shall be the preferred item for all applications.

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- 6.2 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
- 6.3 Comments. Comments on this drawing should be directed to DESC-ECS, Dayton, Ohio 45444, or telephone 513-296-5375.
- 6.4 Approved source of supply. An approved source of supply is listed herein. Additional sources will be added as they become available. The vendor listed herein has agreed to this drawing and a certificate of compliance (see 3.5 herein) has been submitted to DESC-ECS.

Military drawing part number	Vendor CAGE number	Yendor similar part number 1/	Replacement military specification part number
5962-8671101XX	27014	LM113H/883B	
5962-8671102XX	27014	LM113-1H/883B	
5962-8671103XX	27014	LM113-2H/883B	

1/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

Vendor CAGE number

27014

Vendor name and address

National Semiconductor Corporation 2900 Semiconductor Drive Santa Clara, CA 95051

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MILITARY	DRAWING

DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444

SIZE A

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